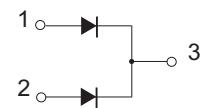
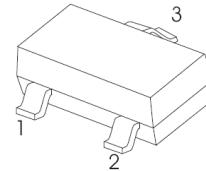


**1SS184**

Switching Diode

**FEATURES**

- Low forward voltage
- Fast reverse recovery time

**SOT-23****Maximum Ratings @Ta=25°C**

Parameter	Symbol	Limit			Unit
<b>Non-Repetitive Peak Reverse Voltage</b>	V <sub>RM</sub>	85			V
<b>DC Blocking Voltage</b>	V <sub>R</sub>	80			V
<b>Forward Continuous Current</b>	I <sub>FM</sub>	300			mA
<b>Average Rectified Output Current</b>	I <sub>O</sub>	100			mA
<b>Power Dissipation</b>	P <sub>D</sub>	150			mW
<b>Junction Temperature</b>	T <sub>J</sub>	150			°C
<b>Storage Temperature Range</b>	T <sub>STG</sub>	-55~+150			°C

**Electrical Characteristics @Ta=25°C**

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
<b>Reverse breakdown voltage</b>	V <sub>(BR)</sub>	80			V	I <sub>R</sub> =100μA
<b>Forward voltage</b>	V <sub>F1</sub>		0.60		V	I <sub>F</sub> =1mA
	V <sub>F2</sub>		0.72		V	I <sub>F</sub> =10mA
	V <sub>F3</sub>		0.9	1.2	V	I <sub>F</sub> =100mA
<b>Reverse current</b>	I <sub>R1</sub>			0.1	uA	V <sub>R</sub> =30V
	I <sub>R2</sub>			0.5	uA	V <sub>R</sub> =80V
<b>Capacitance between terminals</b>	C <sub>T</sub>		0.9	3.0	pF	V <sub>R</sub> =0,f=1MHz
<b>Reverse recovery time</b>	t <sub>rr</sub>		1.6	4.0	ns	I <sub>F</sub> =I <sub>R</sub> =10mA,I <sub>rr</sub> =0.1×I <sub>R</sub>

## ■ Marking

Marking	B3
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## Typical Characteristics

